

In the Claims:

Please amend Claim 39 as indicated below. The status of all pending claims is as follows:

1-38. (Canceled)

39. (Currently Amended) A method for fabricating a liquid crystal display device including a liquid crystal layer clamped between a first substrate and a second substrate, said method comprising the steps of:

- (a) forming a pixel electrode pattern on said first substrate;
- (b) painting a resist film on said pixel electrode pattern;
- (c) exposing and developing said resist film and forming a resist pattern having a shape on said pixel electrode pattern in which multiple branches extend outwardly from both sides of a main stem; stem connecting among the multiple braches;
- (d) conducting an ashing process for said resist pattern; and
- (e) conducting a thermosetting process for said resist pattern;

so that liquid crystal molecules in said liquid crystal layer orient approximately in vertical to a surface of said liquid crystal layer in a non-driving state in which a driving electric field is not applied to said liquid crystal layer, and said liquid crystal molecules orient approximately

in parallel to said surface of said liquid crystal layer in a driving state in which the driving electric field is applied to said liquid crystal layer.

40. (Original) The method as claimed in claim 39, wherein said step (c) includes the step of exposing said resist film at less than double exposure amount of an exposure threshold for said resist film.

41. (Previously Presented) The method as claimed in claim 39, wherein said step (b) includes the step of forming said resist film having such a thickness that a thickness of said resist pattern is in a range from 100 nm to 700nm after said ashing process.

42. (Original) The method as claimed in claim 39, wherein said step (b) includes the step of adjusting a viscosity of said resist film so that a thickness of said resist film is in a range from 600nm to 800nm.

43. (Original) The method as claimed in claim 39, wherein said step (e) includes the step of starting the thermosetting process at a temperature lower than 140°C and gradually rising the temperature up to a thermosetting temperature that is lower than 270°C.

44-74. (Cancelled)